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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In Application of: Alvin D. Compaan et al.)) Group Art Unit: Unassigned
Serial No.: 10/722,643)
Filed: November 26, 2003) Attorney Docket No. 1-24016
For: METHOD OF MAKING DIODE STRUCTURES)))

Commissioner for Patents PO Box 1450 Alexandria, VA 22313-1450

INFORMATION DISCLOSURE STATEMENT

Honorable Sir:

Pursuant to 37 C.F.R. 1.97(b), record is hereby made of information which the Patent Office may wish to consider in connection with its examination of the above-identified application. Copies of such information, excluding the U. S. Patents, as well as a completed PTO-1449 form, are enclosed.

Respectfully submitted.

Ted C. Gillespie Reg. No. 27,981

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U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE INFORMATION DISCLOSURE STATEMENT BY APPLICANT U.S. PATENT DOCUMENTS EXAMINE R DOCUMENT NUMBER ATTY. DOCKET NO. 1-24016 ATTY. DOCKET NO. 1-24016 ATTY. DOCKET NO. 1-24016 ATTY. DOCKET NO. 1-24016 SERIAL NO. 10/722,643 APPLICANT Alvin D. Compaan et al. GROUP Unassigned U.S. PATENT DOCUMENTS NAME CLASS SUBCLASS FILIN IF	
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